

Features

- •Emission wavelength:7.18 μm (Typ.)
- •Output power:20 mW (Min.)
- Threshold current: 1.0 A (Max.)

Applications

•Trace gas analysis (SO₃)



Outline

Quantum Cascade Lasers, using structures of SPC (Single Phonon-Continuum) depopulation and DFB (Distributed Feedback), emit CW (Continuous Wave) mid-IR laser under room temperature.

By controlling the chip's operating temperature through the Peltier element installed in the HHL package, it is possible to tune the emission wavelength without mode hopping while keeping longitudinal single mode operation.

Absolute and characteristics

 $T_{op(qcl)}$ = +20 °C, unless otherwise specified.

-1-1-1-1				
Characteristics	Symbols	Ratings	Units	
Forward current *1)	I _f	This product has individual difference.	Α	
Forward voltage *1)	V_{f}	Confirm data sheet attached to a product *2)	V	
Reverse voltage *1)	V_r	0.0	V	
Change speed of forward current *3)	-	5	mA/s	
TEC current (cooling mode) *4)	I _c	+3.7	Α	
TEC current (heating mode) *4)	ic	-1.5	Α	
TEC voltage	V _c	±13.0	V	
Operating temperature (case) *5) *6)	$T_{op(c)}$	+10 to +60	°C	
Operating temperature (QCL) *7)	$T_{op(qcl)}$	0 to +55	°C	
Change speed of operating temperature '8)	-	10	°C/min	
Storage temperature *5)	T _{stg}	-20 to +65	°C	

- *1) Confirm data sheet attached to a product. Sensitive to electrical surges and instability. Reverse current/voltage cause damage in laser specifications and out of warranty.
- *2) Necessary specifications of power supply : $I_f \ge 1.3$ A, $V_f \ge 16$ V.
- *3) Speed when changing the forward currrent (I_f).
- *4) Even if TEC current ((c) is below the absolute maximum, insufficient heat dissipation from this product may cause damage in laser and TEC specifications and out of warranty. Especially there are possibilities of damage, degradation and less reliability when TEC is operated in heating mode since heated-up side (laser chip) is thermally isolated from case of package and ambience. Refer to schematic configuration in 3-2-4.
- *5) Avoid water condensation.
- *6) Temperatures of case (body) of HHL-package.
- *7) Temperatures of QC-laser when operated; should be monitored by the built-in thermistor for Top(qcl).
- *8) Speed when changing the operation temperature (Top(qcl)) controlled by the built-in TEC.

Specifications (laser)

Characteristics	Symbols	Test conditions	Min.	Тур.	Max.	Units
Operating temperature (QCL) *1)	$T_{op(qcl)}$	K *2)=1392 cm ⁻¹	+10	-	+50	°C
Spectral linewidth *3)	ΔK_L	K *2)=1392 cm-1	-	-	0.2*4)	cm ⁻¹
Wavenumber tuning range *5)	ΔK_T	K *2)=1392 cm-1	±1.0	-	-	cm ⁻¹
Radiant power	Фе	K *2)=1392 cm-1	20	-	-	mW
Threshold current	I _{th}	T _{op(qcl)} =+20 °C	-	-	1.0	Α
Side mode suppression ratio	SMSR	T _{op(qcl)} =+20 °C	25 *4)	-	-	dB

- *1) This product is able to emit the target wavenumber at a certain Top(qc) within the specified temperature range.
- *2) K: Emission wavenumber (cm⁻¹).
- *3) FWHM.
- *4) These values are limited by resolution and singnal-to-noise ratio of instrument when tested
- *5) Continuously wavenumber scan range; Center of the tunability range is the emission wavenumber (K).

TEC

Characteristics	Symbols	Test conditions	Specifications
Maximum temperature difference	ΔT_{max}	$T_h=27 ^{\circ}C$, in N_2 , $Q_c=0$, $I_c=+3.7 A$	>40 °C
Maximum heat pumping capacity	Q _{cmax}	$T_h= 27 ^{\circ}C$, in N_2 , $I_c=+3.7 A$, $\Delta T=0$	>18 W
AC resistance	ACR	T _h =27 °C, I _c =0.1 mA, 1 kHz	2.0 Ω±0.4 Ω

Note) ΔT : Temperature difference

Qc: Heat pumping capacity

Ic: TEC current

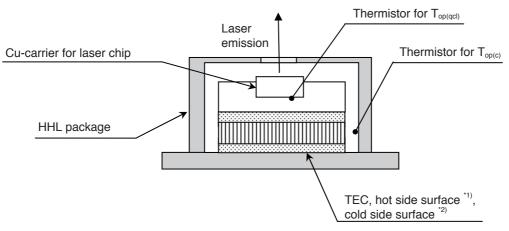
T_h: Temperature of TEC's hot side surface (TEC: cooling mode)

Thermistor

Characteristics	Symbols	Test conditions	Specifications
Resistance	R ₂₅	25 °C	10 kΩ±2.5 %
Beta value	В	0 °C / 100 °C	3450 K

Note) Same specifications for both thermisters of $T_{\text{op(qcl)}}$ and $T_{\text{op(c)}}$.

■ Thermistor configurations (schematic)



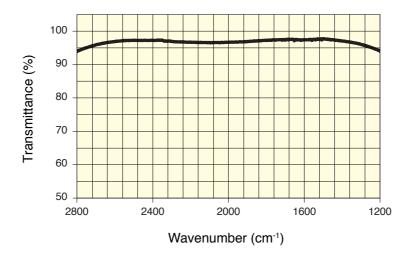
*1): when TEC is operated in cooling mode.
*2): when TEC is operated in heating mode.

■ Window of HHL package

Characteristics		Specifications	
Material		ZnSe, Plano-Plano	
Dimension Clear aperture *1)		ф4.4 mm	
Diffierision	Thickness	0.7 mm	
Coating	Coating	BBAR, both surface	
	Bandwidth	2500 cm ⁻¹ to 1250 cm ⁻¹	
	Transmittance *2)	> 96 %	

^{*1)} Mechanical aperture of HHL package.

■ Typical transmittance curve of the window

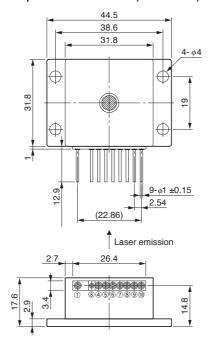


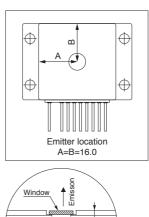
■ Necessary specifications of power supply for the laser (QCL)

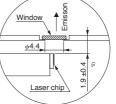
Characteristics	Specifications	
Output current	≥1.3 A	
Output voltage	≥16 V	
Function	Surge protect	
	Constant current control	

^{*2)} Average in the bandwidth.

■ Dimensional outline and pin connection (unit:mm)







- *1) Tolerance is +/- 0.3 mm unless specified.
- *2) Edge of QCL chip and outside of the package.

Pin No. *3)	Function	Pin No. *3)	Function
1	TEC cathode (-)	7	QCL cathode (-)
3	N.C.	8	Thermistor, (T _{op(c)})
4	QCL anode (+)	9	Thermistor, (T _{op(c)})
5	Thermistor, (T _{op(qcl)})	10	TEC anode (+)
6	Thermistor, (T _{op(qcl)})	-	-

^{*3)} Pin of ③ is electrically connected to the case; package body. Other all pins are floating to the case.

CLASS 3B LASER

Invisible Laser Radiation: Avoid Exposure to Beam

The Laser emits invisible laser radiation.
The instrument which used the LASER, operated under ordinary conditions, is classified as Class 3B according to the laser product classification code IEC 60825-1. See IEC 60825-1 for more details and safety operation concerning the above countermeasures.



HAMAMATSU PHOTONICS K.K. www.hamamatsu.com

HAMAMATSU PHOTONICS K.K., Laser Promotion Division, Business Promotion G.

1-8-3, Shinmiyakoda, Kita-ku, Hamamatsu City, Shizuoka, 431-2103, Japan, Telephone: (81)53-484-1301, Fax: (81)53-484-1302, E-mail: sales-laser@lpd.hpk.co.jp

1-8-3, Sninmiyakoda, Kita-ku, Hamamatsu City, Snizuoka, 431-21U3, Japan, 1elephone: (81)53-484-13U1, Fax: (81)53-484-13U2, E-mail: sales-laser@ipd.npk
U.S.A.: Hamamatsu Corporation: 360 Foothill Road, Bridgewater, NJ 08807, U.S.A., Telephone: (1)908-231-0960, Fax: (1)908-231-1218 E-mail: usa@hamamatsu.com
Germany: Hamamatsu Photonics Deutschland GmbH.: Arzbergerstr. 10, D-82211 Herrsching am Ammersee, Germany, Telephone: (49)8152-375-0, Fax: (49)8152-265-8 E-mail: info@hamamatsu.de
France: Hamamatsu Photonics France S.A.R.L.: 19, Rue du Saule Trapu, Parc du Moulin de Massy, 91882 Massy Cedex, France, Telephone: (33)1 69 53 71 00, Fax: (33)1 69 53 71 10 E-mail: info@hamamatsu.fr
United Kingdom: Hamamatsu Photonics UK Limited: 2 Howard Court, 10 Tewin Road, Welwyn, Road, Old Perentrofshire ALT 18W, UK, Telephone: (44)1707-29488, Fax: (44)1707-325777 E-mail: info@hamamatsu.co.uk
North Europe: Hamamatsu Photonics Norden AB: Torshamnsgatan 35 16440 Kista, Sweden, Telephone: (46)8-509 031 00, Fax: (46)8-509 031 01 E-mail: info@hamamatsu.se
Italy: Hamamatsu Photonics Italia S.r.l.: Strade della Moia, 1 int. 6, 20020 Arese (Millano), Italy, Telephone: (39)02-93 58 17 33, Fax: (39)02-93 58 17 41 E-mail: info@hamamatsu.com.cn
Talwan: Hamamatsu Photonics Taiwan Co., Ltd.: 8F-3, No.158, Section2, Gongdao 5th Road, East District, Hsinchu, 300, Taiwan R.O.C. Telephone: (886)3-659-0081 E-mail: info@hamamatsu.com.cn